Simulation of 2D Silicon MESFET using GNU/Archimedes

J.M.Sellier¹

Dipartimento di Matematica e Informatica, Universita' di Catania, Italy, sellier@dmi.unict.it, www.gnu.org/software/archimedes

Summary. GNU/Archimedes is the GNU Free Software for the design and simulation of Semiconductor devices. Here we show, briefly, how it is possible to simulate a 2D Silicon MESFET just typing a very simple script describing the MESFET. All the relevant scattering phenomena are taken into account in order to obtain a realistic simulation of the Electron-Dynamics. You can find the GNU/Archimedes package at the following web site: www.gnu.org/software/archimedes

1.1 Introduction

Using GNU/Archimedes is very simple. Indeed, in order to describe a semiconductor device, one only needs to type a brief script in which the description of the device is reported in a simple scripting language. We report, in the following, a brief script usefull for the simulation of a 2D Silicon MESFET.

- # Silicon MESFET test-1
- # created on 22 sep.2004, J.M.Sellier
- # modified on 21 oct.2004, J.M.Sellier

MATERIAL SILICON
TRANSPORT ELECTRONS

FINALTIME 6.0e-12 TIMESTEP 0.0015e-12

XLENGTH 0.6e-6 YLENGTH 0.2e-6

XSPATIALSTEP 120 YSPATIALSTEP 40

```
# Definition of the doping concentration
# -----
           0. 0. 0.6e-6
0. 0.15e-6 0.1e-6
DONORDENSITY O.
                                       0.2e-6
DONORDENSITY
                                       0.2e-6
DONORDENSITY 0.5e-6 0.15e-6 0.6e-6
                                       0.2e-6
ACCEPTORDENSITY O.
                     0.
                              0.6e-6
                                       0.2e-6
# Definition of the various contacts
CONTACT DOWN 0.0
                 0.6e-6 INSULATOR 0.0
CONTACT LEFT 0.0 0.2e-6 INSULATOR 0.0
CONTACT RIGHT 0.0 0.2e-6 INSULATOR 0.0
CONTACT UP 0.1e-6 0.2e-6 INSULATOR 0.0
CONTACT UP
         0.4e-6 0.5e-6 INSULATOR 0.0
         0.0 0.1e-6 OHMIC
CONTACT UP
                              0.0 3.e23
CONTACT UP
          0.2e-6 0.4e-6 SCHOTTKY -1.3
CONTACT UP 0.5e-6 0.6e-6 OHMIC 1.0 3.e23
NOQUANTUMEFFECTS
MAXIMINI
# SAVEEACHSTEP
LATTICETEMPERATURE 300.
STATISTICALWEIGHT 1000
MEDIA 500
```

1.e23

3.e23

3.e23

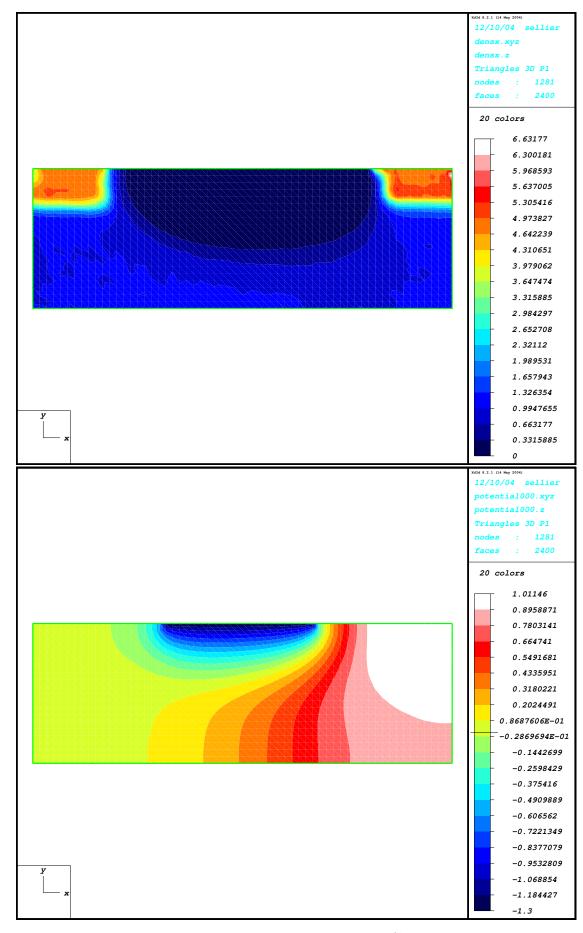
1.e20

OUTPUTFORMAT GNUPLOT

end of MESFET test-1

1.2 GNU/Archimedes Simulation Results

We report, in the following, some pictures which show the results obtainable with GNU/Archimedes.



 ${\bf Fig.~1.1.~Plot~of~the~MESFET~density~and~potential~obtained~by~GNU/Archimedes.}$

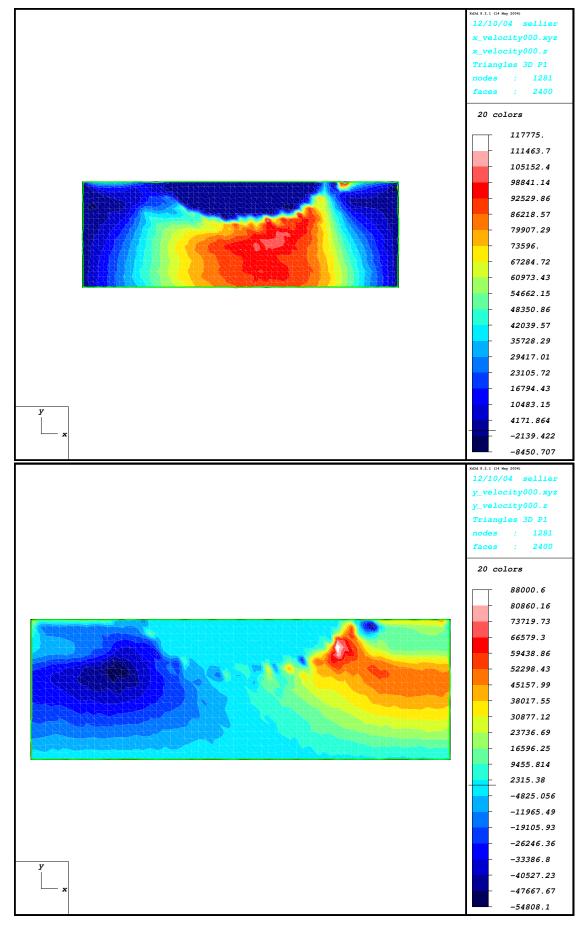


Fig. 1.2. Plot of the MESFET x and y-component of velocity obtained by GNU/Archimedes.

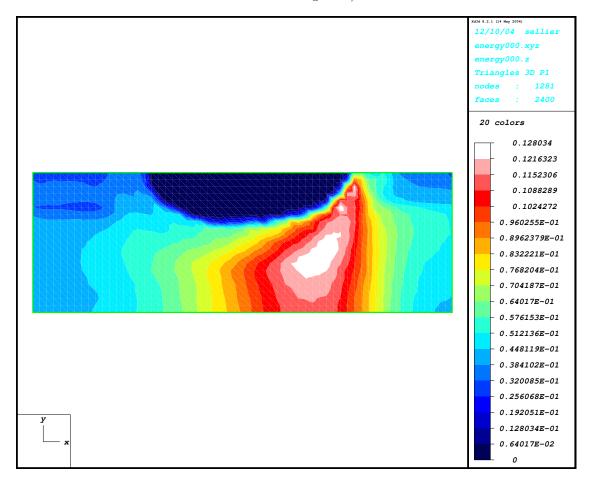


Fig. 1.3. Plot of the MESFET electron energy obtained by GNU/Archimedes.